

SSD0804 Series Unshielded SMD Power Inductors





◆特征:

- 具有高功率,高饱和低直流电阻
- 非屏蔽功率电感
- 适用于表面贴装设备
- 多种封装尺寸和宽电感范围
- 符合 RoHS,无卤和 REACH

◆用途:

- 笔记本电脑
- 家用电器等
- DC/DC 转换器等

◆环境:

• 工作温度: -40℃ 至+125℃ (包括线圈自身温升)

◆试验设备:

- 电感值:HP4284A, HP4285A 或同等仪器
- 电流:HP4284+42841A 或同等仪器
- 自谐振频率:Agilent E4991A 或同等仪器
- 直流电阻: Chroma 16502 或同等仪器

▶产品型号:

SSD

(4)

0804
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	类型 Type
	非屏蔽磁路贴片电感
SSD	Unshielded SMD T

公差 Inductance Tolerance

J:±5%,K: ±10%, L: ±15% M: ±20%,P: ±25%, N: ±30%

Features:

- High power, High saturation, Low resistance
- Unshielded power inductor
- Suitable for surface mounting equipment
- Various package size and wide inductance range
- RoHS, Halogen Free and REACH Compliance

Applications:

- Power supply for VTRs
- LCD televisions
- DC/DC converters, etc

Environmental Data:

 Operating Temperature: -40 ℃ to +125 ℃ (Including coils self-temperature rise)

Test Equipment:

- L:HP4284A or HP4285A LCR meter or equivalent
- Isat & Irms: HP4284+42841A or equivalent
- SRF:Agilent E4991A or equivalent
- DCR:Chroma 16502 or equivalent

Product Identification:

	2	× ×				
5	外形尺寸(L×W×H) (mm)					
	External Dimensions (L×W×H)					
	(mm)				
	0804	12.95×9.4×5.21				

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(mm)					
0804	12.95×9.4×5.21				

(3) Inductance 10 uH

(5)

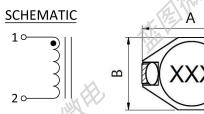
包装 Packing							
В	散装Bulk Package						
Т	编带Tape & Reel	1					

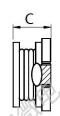


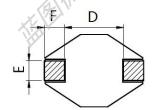


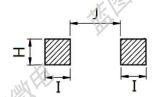
◆外观尺寸:

Shape and Dimensions (dimensions are in mm):









Recommended Land Pattern

Part No		A		ITEM					
Partino	A	В	С	D	uk ÉS	F	Н	I	J
SSD0804	12.95 Max	9.4 Max	5.21 Max	7.62	2.54	2.54	2.79	2.92	7.37

◆规格特性:

Specifications:

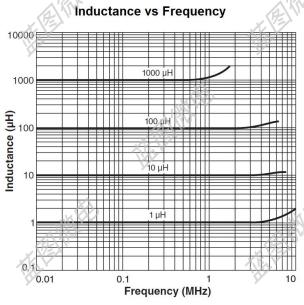
• SSD0804 Series Electrical Characteristics (Electrical specifications at 25°C)

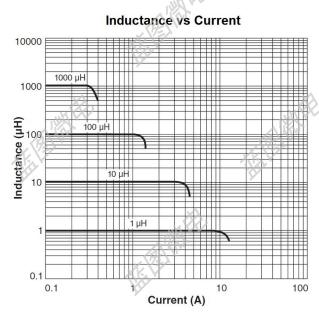
Inductance			SRF	DCR	Saturation Current	Temperature Rise Current	
L(μH) '@0A	Tole	Test Freq	MHz Typ	(Ω) Max	(A) Max	(A) Max	
1.0	±20%	100KHz	100	0.009	9.00	6.80	
1.5	±20%	100KHz	90	0.010	8.00	6.40	
2.2	±20%	100KHz	80	0.012	7.00	6.10	
3.3	±20%	100KHz	65	0.015	6.40	5.40	
4.7	±20%	100KHz	45	0.018	5.40	4.80	
6.8	±20%	100KHz	38	0.027	4.60	4.40	
10	±20%	100KHz	30	0.038	3.80	3.90	
15	±20%	100KHz	27	0.046	3.50	3.10	
22	±20%	100KHz	19	0.085	3.00	2.70	
33	±20%	100KHz	15	0.100	2.60	2.10	
47	±20%	100KHz	12	0.140	2.00	1.60	
68	±20%	100KHz	10	0.200	1.60	1.40	
100	±20%	100KHz	9	0.280	1.40	1.20	
150	±10%	100KHz	6	0.400	1.20	1.00	
220	±10%	100KHz	5	0.610	1.00	0.80	
330	±10%	100KHz	4.5	1.020	0.60	0.60	
470	±10%	100KHz	3.5	1.270	0.50	0.50	
680	±10%	100KHz	2.5	2.020	0.40	0.40	
1000	±10%	100KHz	2.0	3.000	0.30	0.30	
	L(μH) '@0A 1.0 1.5 2.2 3.3 4.7 6.8 10 15 22 33 47 68 100 150 220 330 470 680	L(μH) Tole '@0A 1.0 ±20% 1.5 ±20% 2.2 ±20% 3.3 ±20% 4.7 ±20% 6.8 ±20% 10 ±20% 15 ±20% 22 ±20% 33 ±20% 47 ±20% 68 ±20% 100 ±20% 150 ±10% 220 ±10% 330 ±10% 470 ±10% 680 ±10%	L(μH) Tole Freq 1.0 ±20% 100KHz 1.5 ±20% 100KHz 2.2 ±20% 100KHz 3.3 ±20% 100KHz 4.7 ±20% 100KHz 6.8 ±20% 100KHz 10 ±20% 100KHz 15 ±20% 100KHz 22 ±20% 100KHz 33 ±20% 100KHz 47 ±20% 100KHz 47 ±20% 100KHz 47 ±20% 100KHz 47 ±20% 100KHz 48 ±20% 100KHz 49 100KHz 4100 ±20% 100KHz 100 ±10% 100KHz 100 ±10% 100KHz 100KHz	L(μH) Tole Freq Typ 1.0 ±20% 100KHz 100 1.5 ±20% 100KHz 90 2.2 ±20% 100KHz 65 4.7 ±20% 100KHz 45 6.8 ±20% 100KHz 38 10 ±20% 100KHz 30 15 ±20% 100KHz 27 22 ±20% 100KHz 19 33 ±20% 100KHz 19 33 ±20% 100KHz 15 47 ±20% 100KHz 15 47 ±20% 100KHz 15 47 ±20% 100KHz 10 100 ±20% 100KHz 9 150 ±10% 100KHz 9 150 ±10% 100KHz 5 330 ±10% 100KHz 5 330 ±10% 100KHz 5 330 ±10% 100KHz 5 330 ±10% 100KHz 4.5 470 ±10% 100KHz 3.5	L(μH) Tole Test MHz (Ω)	Current Current	





- Saturation Current: DC current at which inductance drops 10% from its value without current.
- Temperature Rise Current: the actual value of DC current when the temperature rise is ΔT 40°C (Ta=25°C)
- Rated DC Current: The less value which is Isat or Irms.
- Special remind: Circuit design, component, PCB trace size and thickness, airflow and other cooling provisions all affect the part temperature. Part temperature should be verified in the end application.
- Frequency VS Saturation current

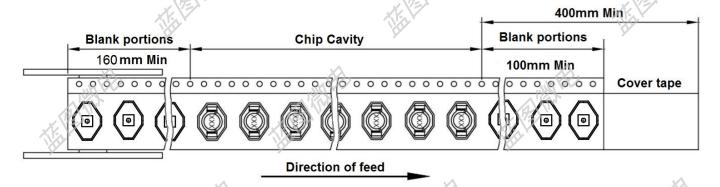




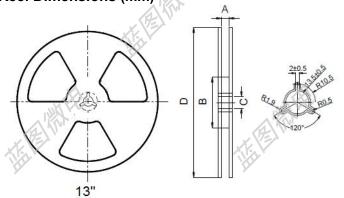
◆产品包装:

Packaging:

• Tape and Reel Specifications: (Dimensions are in mm)



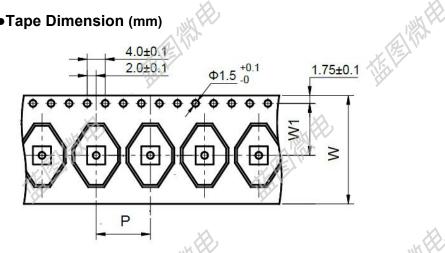
• Reel Dimensions (mm)





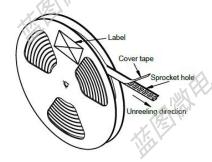


●Tape Dimension (mm)

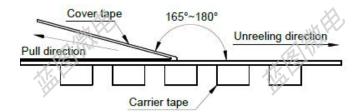


Tape Dimension			Reel Dimensions			REEL	Inside	Outside		
Part No.	W P W1		Α	В	C.	D	(PCS)	Box(PCS)	Carton(PCS)	
SSD0804	24	16	11.5	24.4	100	13	330	1000	2000	8000

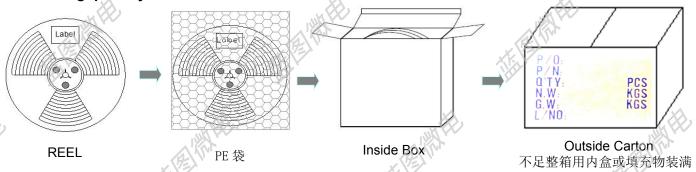
• Cover tape peel off condition



- a) Cover tape peel force shall be 10 to 120g
- b) Noodle strip peeling angle165° to 180°



• Packing quantity







◆可靠性测试:

Reliability Testing:

▼ 1.1 de 1.7 m/·		Trondbinty resting.			
Items	Requirements	Test Methods and Remarks			
Terminal Strength Reference docu ments: GB/T 2423 60-2008 端子強度(SMT)	1. Pulling test: Define: A: sectional area of terminal A ≤ 8mm2 force ≥ 5N time:30sec 8mm2 <a 10n="" 10sec="" 2.solder="" 20mm2="" 20mm2<a="" 20n="" 3.meet="" above="" any="" force="" loose="" paste="" requirements="" td="" terminal<="" the="" thickness:0.12mm="" time:="" without="" ≤="" ≥=""><td>Solder the inductor to the testing jig using leadfree solder. Then apply a force in the Keep time: 10±1s Speed: 1.0mm/s.</td>	Solder the inductor to the testing jig using leadfree solder. Then apply a force in the Keep time: 10±1s Speed: 1.0mm/s.			
erminal Strength Reference docu ments: GB/T 2423.60-2008 端子強度(DIP)	1.Terminal diameter(d) mm 0.35 < d ≤ 0.50 Applied force:5N Duration: 10sec2.Terminal diameter(d) mm0.50 < d ≤ 0.80 Applied force:10N Duration: 10sec3.Terminal diameter(d) mm0.80 < d ≤ 1.25 Applied force:20N Duration: 10sec4.Terminal diameter(d) mmD > 1.25 Applied force:40N Duration: 10sec5.Meet the above requirements without any loose terminal.	Pull Force:the force shall be applied gradually to the terminal and thenmaintained for 10 seconds. F Pulling test			
Resistance to Flexure JIS C 5321:1997 抗弯曲性试验	1.No visible mechanical damage.	1.Solder the inductor to the test jig (glass epoxy board 2.shown in Using a leadfree solder. Then apply a force in the direction shown 3.Flexure: 2mm. 4.Pressurizing Speed: 0.5mm/sec. 5.Keep time: 30 sec.			
Dropping Reference documents:	Sy	1.Drop the packaged products from 1m high in 1 angle, 3 ridges and 6surfaces, twice in each			
GB/T 2423.7-2018 落下試驗	2.No short and no open.	direction.			
Solderability Reference documents: GB/T 2423.28-2005 可焊性试验	3. Terminals must have 95% minimum solder	 1.Solder temperture:240±2℃ 2.Duration: 3 sec. 3. Solder: Sn/3.0Ag/0.5Cu. 4.Flux: 25% Resin and 75% ethanol in weight 			





Items	Requirements	Test Methods and Remarks
Vibration Reference documents: GB/T 2423.10-2019 振動試验	1. No visible mechanical damage. 2. Inductance change: Within ±10%. 3. Q factor change: Within ±20%. Cu pad Solder mask Glass Epoxy Board	1.Solder the inductor to the testing jig (glass epoxy boardshown in) using leadfree solder. 2.The inductor shall be subjected to a simple harmonic motion having total amplitude of 1.5mm, the frequency being varieduniformly between the approximate limits of 10 and 55 Hz. 3.The frequency range from 10 to 55 Hz and return to 10 Hz shallbe traversed in approximately 1 minute. This motion shall be applied for a period of 2 hours in each 3mutually perpendicular directions(total of 6 hours).
提上	提展機構	55Hz 10Hz 0 1Min Time
	1.No visible mechanical damage.	1.Start at (85∼125℃) for T time, rush to
	2. Inductance change: Within ±10%.(Mn-Zn:	(-55~40℃) for T time as one cycle, go through100
	Within ≤ 30%)	cycles.
Thermal Shock	3 Q factor change: Within ±20%.	2.Transforming interval: Max. 20 sec.
Reference documents:	Mil.	3.Tested cycle: 100 cycles.
GB/T 2423.22-2012		4.The chip shall be stabilized at normal condition
Method Na 冷热冲击试验	描描黑/概样	for 1~2 hours 125 °C/85 °C Ambient Temperature -55 °C/-40 °C 20sec. (max.)
		and the
	1.No visible mechanical damage.	1.Temperature:M(-55~-40±2℃)
	2. Inductance change: Within ±10%.(Mn-Zn:	2.Duration: 96±2 hours
Low temperature Storage	Within ≦30%)	3.The chip shall be stabilized at normal condition for
Reference documents:	3.Q factor change: Within ±20%.	1~2 hoursbefore measuring.
GB/T 2423.1-2008	1 WY PE	Room
Method Ab 低温储存试验	THE PERSON NAMED IN THE PE	Temp 0 96H Test 97H 98H Time Low temperature





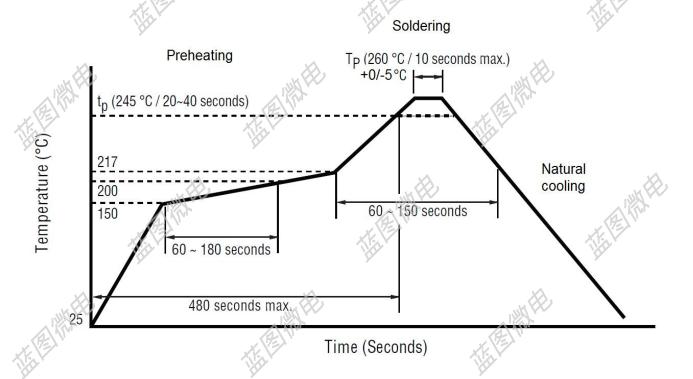
Items	Requirements	Test Methods and Remarks
High temperature	No visible mechanical damage. Inductance change: Within ±10%.(Mn-Zn:	1.Temperature:N(125~85±2℃). 2.Duration: 96±2 hours
Storage Reference documents: GB/T 2423.2-2008 Method Bb 高温储存试验 Damp Heat (Steady States) Reference documents: GB/T 2423.3-2016 恒定湿热试验	Within ≤30%) 3.Q factor change: Within ±20% 1.No visible mechanical damage. 2. Inductance change: Within ±10%.(Mn-Zn: Within ≤30%) 3.Q factor change: Within ±20%.	3. The chip shall be stabilized at normal condition for 1~2 hoursbefore measuring. Temp N°C Room Temp 1. Temperature: 60±2°C 2. Humidity: 90% to 95% RH. 3. Duration: 96±2 hours. 4. The chip shall be stabilized at normal condition for 1~2 hoursbefore measuring. Temp 60°C 93%RH Room Conditions
Heat endurance of Reflow soldering Reference documents: GJB 360B-2009 回流焊耐热性试验	1.No significant defects in appearance. 2. △ L/L ≦ 10% (Mn-Zn: △ L/L ≦ 30%) 3. △ Q/Q ≦ 30% (SMD series only) 4. △ DCR/DCR ≦ 10%	1.Refer to the above reflow curve and go through the reflow for twice. 2.The peak temperature : 260+0/-5℃
Resistance to solvent test Reference documents: IEC 68-2-45:1993 耐溶剂性试验	No case deformation or change in appearance or obliteration of marking	To dip parts into IPA solvent for 5±0.5Min,then drying them at room temp for 5Min,at last ,to brushing making 10 times.
	1.During the test no smoke, no peculiar, smell, no fire 2.The characteristic is normal after test	Apply twice as rated current for 5 minutes.
voltage resistance test Reference documents: MIL-STD-202G Method 301 绝缘耐压测试	During the test no breakdown The characteristic is normal after test	For parts with two coils DC1000V, Current: 1mA, Time: 1Min. Refer to catalogue of specific products





◆推荐回流焊温度曲线

Recommended reflow soldering curve:



The recommended reflow conditions as above graph, is set according to our soldering equipment. DUE to various manufactures may have different reflow soldering equipment, products, process conditions, set methods. And so on, when setting the reflow conditions, Please adjust and confirm according to users' environment/equipment.



使用注意事项

REMINDERS FOR USING THESE PRODUCTS



● 保存时间为12 个月以内,保存条件(温度5~40°C以下、湿度35 ~ 66%RH 以下),需充分注意 若超过保存时间,端子电极的可焊性将可能老化。

The storage period is within 12 months. Be sure to follow the storage conditions (temperature: 5~40°C, humidity: 35 to 65% RH or less). If the storage period elapses, the soldering of the terminal electrodes may deteriorate.

● 请勿在气体腐蚀环境(盐、酸、碱等)下使用和保存。

Do not use or store in locations where there are conditions such as gas corrosion (salt, acid, alkali, etc.).

手上的油脂会导致可焊性降低,应避免用手直接接触端子。
 Don't touch electrodes directly with bare hands as oil secretions may inhibit soldering Always ensure optimum conditions for soldering。

- 请小心轻拿轻放,避免由于产品的跌落或取出不当而导致的损坏。
 Please always handle products carefully to prevent any damage caused bydropping down or inappropriate removing。
- 端子过度弯曲会导致断线,请不要过度弯曲端子。
 Don't bend the terminals with excessive stress in case of any wire fracture。
- 不要清洗产品,如需要清洗时请联系我司。
 Don't rinse coils by yourself and please contact SXN if necessary。
- 请勿将本产品靠近磁铁或带有磁力的物体
 Don't expose the products to magnets or magnetic fields
- 在实施焊接前,请务必进行预热。预热温度与焊接温度及芯片温度的温度差要在150°C 以内。 Before soldering, be sure to preheat components. The preheating temperature should be set so that the temperature difference between the solder temperature and chip temperature does not exceed 150°C.
- 安装后的焊接修正应在规格书规定的条件范围内。若加热过度可能导致短路、性能降低、寿命减少。 Soldering corrections after mounting should be within the range of the conditions determined in the specifications. If overheated, a short circuit, performance deterioration, or lifespan shortening may occur.
- 装置会因通电而自我发热(温度上升),因此在热设计方面需留有充分余地。
 Self heating (temperature increase) occurs when the power is turned ON, so the tolerance should be sufficient for the set thermal design.
- 非磁屏蔽型在基板设计时需注意配置线圈,受到电磁干扰可能会导致误动作。
 Carefully lay out the coil for the circuit board design of the non-magnetic shield type. A malfunction may occur due to magnetic interference.